



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Docket: INT 0001A

~~In re~~ patent application of
Michael David Church

~~Serial~~ No. 10/026,294

~~Filed~~: 12-20-01

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)
) Group Art Unit: 2823

)
) Examiner: Nguyen, Khiem

~~Title~~: A Method of Fabricating Enhanced EPROM Structures with
Accentuated Hot Electron Generation Regions

BOX AMENDMENTS

Assistant Commissioner for Patents
Washington, D.C. 20231

AMENDMENT B

Applicant has received an Official Action, mailed 10-24-02, to co-pending
Application Serial Number: 10/026,345, filed on 12-20-01. The cited prior art is enclosed
herewith on PTO form 1449.

The co-pending application is based on the same specification as this application.

In response to the Office Action (mailed on 12-13-02), please amend the above-
identified application as follows:

In the claims:

1. (Amend) A process for making a semiconductor device comprising the steps of:

performing a LOCOS operation on an epitaxial layer of a semiconductor substrate to

define an active region having a predefined boundary:

#7/Andt B
R. Tyson
2/25/03
FEB 12 2003
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